Day: Wednesday



# **PALM INTRANET**

Date: 4/12/2006 Time: 07:16:50

#### **Inventor Name Search Result**

Your Search was:

Last Name = SATOH First Name = SHINICHI

Application#	Patent#	Status	Date Filed	Title	Invent Name
06454273	4478376	150	1	METHOD OF WINDING MAGNETIC RECORDING TAPE	SATOI SHINI
06694322	Not Issued	166	01/24/1985	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
06849759	4680598	150	04/08/1986	CHROMOGENIC MATERIALS EMPLOYING FLUORAN COMPOUNDS	SATOI SHINI
06904119	4753158	150	09/05/1986	PILOT HYDRAULIC SYSTEM FOR OPERATING DIRECTIONAL CONTROL VALVE	SATOI SHINI
<u>06918472</u>	4687862	150	10/14/1986	FLUORAN COMPOUNDS	SATOI SHINI
<u>07047607</u>	Not Issued	166	05/01/1987	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
07067178	Not Issued	161	06/29/1987	ROOM TEMPERATURE CURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07079050	Not Issued	161	07/29/1987	ORGANIC SILICON COMPOUNDS	SATOI SHINI
07092000	4801725	150	09/02/1987	ORGANOSILICON COMPOUND	SATOI SHINI
07094647	Not Issued	166	09/09/1987	SEMICONDUCTOR MEMORY CELLS HAVING COMMON CONTACT HOLE	SATOI SHINI
07101427	4875337	150	09/28/1987	CONSTRUCTION MACHINE DUAL-PUMP HYDRAULIC CIRCUIT WITH PILOTED ARM-BOOM CYLINDER SUPPLY RRIORITY SWITCHING VALVES	SATOI SHINI
07143400	4905068	150		SEMICONDUCTOR DEVICE HAVING INTERCONNECTION LAYERS OF T- SHAPE CROSS SECTION	SATOI SHINI
<u>07150166</u>	4892895	150	01/29/1988	ULTRAVIOLET-CURABLE ORGANOPOLYSILOXANE	SATOI SHINI

				COMPOSITION	
07170028	4887137	250	03/04/1988	SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
<u>07196011</u>	4832082	150	04/22/1988	HYDRAULIC PILOT OPERATED DIRECTIONAL CONTROL VALVE	SATOI SHINI
07216023	4861908	150	07/07/1988	ORGANOSILICON COMPOUND	SATOI SHINI
07216163	4960847	150	07/07/1988	ROOM TEMPERATURE VULCANIZABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07221509	4858649	150	04/29/1988	VALVE APPARATUS	SATOI SHINI
07232551	Not Issued	166	08/15/1988	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
07242116	5089863	150	09/08/1988	FIELD EFFECT TRANSISTOR WITH T- SHAPED GATE ELECTRODE	SATOI SHINI
07261022	5027173	150	10/20/1988	SEMICONDUCTOR MEMORY DEVICE WITH TWO SEPARATE GATES PER BLOCK	SATOI SHINI
07317721	Not Issued	168	03/02/1989	PHOTOCURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07337723	5014110	150	04/12/1989	WIRING STRUCTURES FOR SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
07358495	4984199	150	II	SEMICONDUCTOR MEMORY CELLS HAVING COMMON CONTACT HOLE	SATOI SHINI
07364033	5047817	150	06/09/1989	STACKED CAPACITOR FOR SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
07376662	Not Issued	166		FIELD SHIELD ISOLATION STRUCTURE FOR SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI(
07377998	5093706	150		SEMICONDUCTOR DEVICE HAVING MULTIPLE LAYER RESISTANCE LAYER STRUCTURE AND MANUFACTURING METHOD THEREFOR	SATOI SHINI
07391008	5067000	150	08/09/1989	SEMICONDUCTOR DEVICE HAVING FIELD SHIELD ISOLATION	SATOI SHINI
07405284	4994893	150	09/11/1989	FIELD EFFECT TRANSISTOR HAVING SUBSTANTIALLY COPLANAR SURFACE STRUCTURE	SATOI SHINI
07409379	5097310	150	11	COMPLEMENTARY SEMICONDUCTOR DEVICE HAVING IMPROVED DEVICE ISOLATING REGION	SATOI SHINI

07421568	Not Issued	163	10/11/1989	SEMICONDUCTOR DEVICE HAVING IMPROVED SOURCE AND DRAIN CONTACT REGIONS AND MANUFACTURING METHOD THEREFOR	SATOI SHINI
07425017	5177571	150	10/23/1989	AN LDD MOSFET WITH PARTICULARLY SHAPED GATE ELECTRODE IMMUNE TO HOT ELECTRON EFFECT	SATOI SHINI
<u>07434692</u>	5051948	250	10/20/1989	CONTENT ADDRESSABLE MEMORY DEVICE	SATOI SHINI
07436998	Not Issued	166	11/15/1989	SEMICONDUCTOR DEVICE HAVING FIELD SHIELD ELEMENT ISOLATING STRUCTURE AND METHOD OF MANUFACTURING THE SAME	SATOI SHINI
07446560	4998161	150	12/05/1989	LDD MOS DEVICE HAVING AN ELEMENT SEPARATION REGION HAVING AN ELECTROSTATIC SCREENING ELECTRODE	SATOI SHINI
07450769	Not Issued	166	11	SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME	SATOI SHINI
07473762	5064898	150	02/02/1990	ROOM TEMPERATURE-CURABLE ORGANOPOLYSILOXANE COMPOSITION AND METHOD FOR THE PREPARATION THEREOF	SATOI SHINI
07475870	5087683	150	02/06/1990	PROCESS FOR PRODUCING ALPHA, BETA - HYDROXYFLUOROALKYLPOLYSILOXANES	SATOI SHINI
<u>07515416</u>	5124469	150	04/27/1990	ORGANOSILICON COMPOUND	SATOI SHINI
07526943	5049959	150	II .	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
07538817	5084752	150	06/15/1990	SEMICONDUCTOR DEVICE HAVING BONDING PAD COMPRISING BUFFER LAYER	SATOI SHINI
07555787	Not Issued	164	07/19/1990	PHOTOCURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07562318	5126420	150	08/03/1990	RTV ORGANOPOLYSILOXANE COMPOSITIONS	SATOI SHINI
07562320	5101057	150	08/03/1990	FLUORINATED CARBOXYLIC ACID DERIVATIVES AND METHODS FOR MAKING	SATOI SHINI
07562321	5194648	150	08/03/1990	FLUORINATED CARBOXYLIC ACID	SATO

				DERIVATIVES AND METHODS FOR MAKING	SHINI
07606276	5094965	150	10/31/1990	FIELD EFFECT TRANSISTOR HAVING SUBSTANTIALLY COPLANAR SURFACE STRUCTURE AND A MANUFACTURING METHOD THEREFOR	SATOI SHINI
07614963	5225704	150		FIELD SHIELD ISOLATION STRUCTURE FOR SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI
07637434	Not Issued	166	01/04/1991	SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI
07657261	5164803	250	02/19/1991	CMOS SEMICONDUCTOR DEVICE WITH AN ELEMENT ISOLATING FIELD SHIELD	SATOI SHINI
07661381	5089649	150	04/27/1990	ORGANOSILICON COMPOUND	SATOI SHINI

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	"efficiently teastable display driving circuit".ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:19
L2	33	satoh.in. and oki.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:31
L3	4027517	displa\$4 EL\$4 LED\$4 electroluminescen\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:23
L4	2624431	switch\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:32
L5	191194	measur\$5 near3 (electric\$5 paramete\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:34
L6	403	(3 same 4 same 5).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:38
L7	46827	test\$5 near3 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:08
L8	0	(3 same 4 same 5 same 7).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:39
L9	0	((3 same 4 same 5) and 7).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:39

L10	8	(3 same 4 same 5 same 7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:24
L13	11232	test\$5 near2 (automatical\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:33
L14	3	(3 same 4 same 5 same 13)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:27
L15	200	(3 same 4 same 13)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:27
L16	37	(3 same 4 same 13).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:36
L17	30392	(test\$5 measur\$9) near2 (automatical\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:33
L18	511746	(data\$3 signal\$4) same gate\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:35
L19	49	(17 same 4 same 18)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:40
L20	474	(17 same 4 same 3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:40
L21	105	20 and 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:42

L22	11	20 same 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:41
L23	19	(3 same 4 same 5 same 17)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:06
L24	97366	(test\$5 measur\$8) near3 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:10
L25	22	(3 same 4 same 5 same 24)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:26
L26	128548	(test\$5 measur\$8) near5 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:14
L27	29	(3 same 4 same 5 same 26)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:15
L28	7	27 not 25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:21
L29	198226	(test\$5 measur\$8) with (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:14
L30	45	(3 same 4 same 5 same 29)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:15
L31	16	30 not 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:21

L32	1671645	EL\$4 LED\$4 electroluminescen\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:23
L33	1	(32 same 4 same 5 same 7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:25
L34	9	(32 and (4 same 5 same 7))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:25
L35	3	(32 same 4 same 5 same 24)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:27